

Temperature dependence of the ionization coefficients of InAlAs and AlGaAs digital alloy: erratum

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The authors made a mistake in omitting the name of co-author Min Ren in Ref. [1].

REFERENCE

1. Y. Yuan, J. Zheng, Y. Tan, M. Ren, Y. Peng, A.-K. Rockwell, S. R. Bank, A. W. Ghosh, and J. C. Campbell, "Temperature dependence of the ionization coefficients of InAlAs and AlGaAs digital alloy," *Photon. Res.* **6**, 794–799 (2018).